TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# 2SK2036

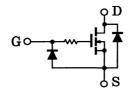
# High Speed Switching Applications Analog Switching Applications

- High input impedance.
- Low gate threshold voltage:  $V_{th} = 0.5 \sim 1.5 \text{ V}$
- Excellent switching times:  $t_{on} = 0.28 \mu s$  (typ.)
  - $t_{\rm off}$  = 0.34  $\mu s$  (typ.)
- Small package
- Enhancement-mode

# Marking

### **Equivalent Circuit**

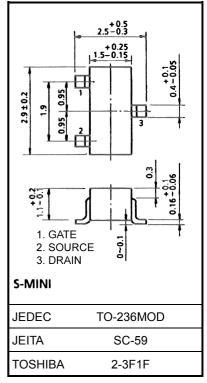




#### **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	20	V
Gate-source voltage	V <sub>GSS</sub>	10	V
Drain current	I <sub>D</sub>	100	mA
Drain power dissipation	P <sub>D</sub>	200	mW
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Unit: mm



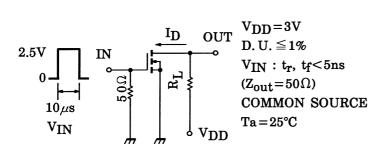
Weight: 0.012 g (typ.)

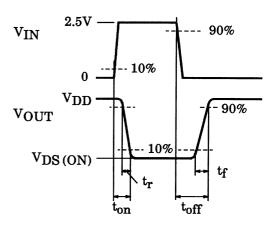
Note: This transistor is electrostatic sensitive device. Please handle with caushon.

## **Electrical Characteristics (Ta = 25°C)**

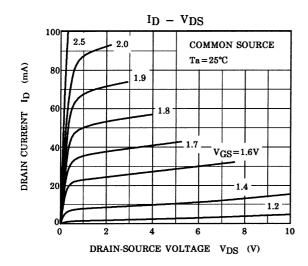
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0	_	_	1	μА
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	$I_D = 100 \ \mu A, \ V_{GS} = 0$	20	_	_	V
Drain cut-off curre	ent	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	_	_	1	μА
Gate threshold vo	Itage	V <sub>th</sub>	$V_{DS} = 3 \text{ V}, I_{D} = 0.1 \text{ mA}$	0.5	_	1.5	V
Forward transfer a	admittance	Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, I_{D} = 10 \text{ mA}$	35	62	_	mS
Drain-source ON	resistance	R <sub>DS</sub> (ON)	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	3.5	6	Ω
Input capacitance		C <sub>iss</sub>	$V_{DS} = 3 V$ , $V_{GS} = 0$ , $f = 1 MHz$	_	14	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 3 V$ , $V_{GS} = 0$ , $f = 1 MHz$	_	5.3	_	pF
Output capacitance		Coss	$V_{DS} = 3 V$ , $V_{GS} = 0$ , $f = 1 MHz$	_	16	_	pF
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \sim 2.5 \text{ V}$	_	0.28	_	μЅ
	Turn-off time	t <sub>off</sub>	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0~2.5 \text{ V}$	_	0.34	_	

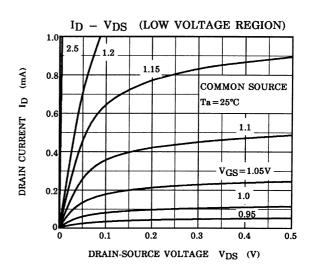
# **Switching Time Test Circuit**

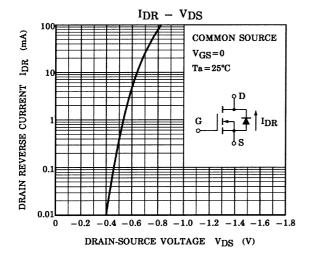


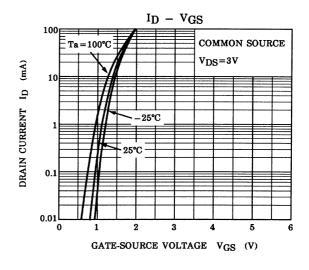


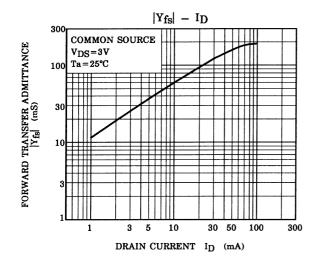
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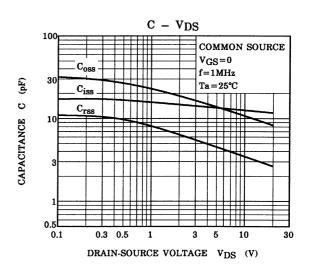




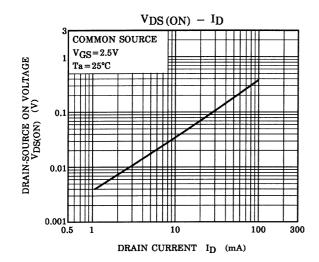


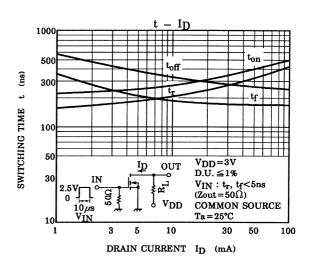


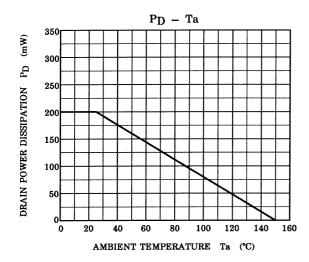




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